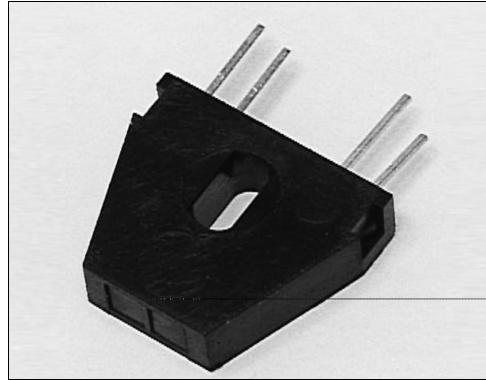


# HOA0708/0709

## Reflective Sensor

### FEATURES

- Choice of phototransistor or photodarlington output
- Focused for maximum response
- Ambient light and dust protective filter
- Adjustable mounting slot



INFRA-56.TIF

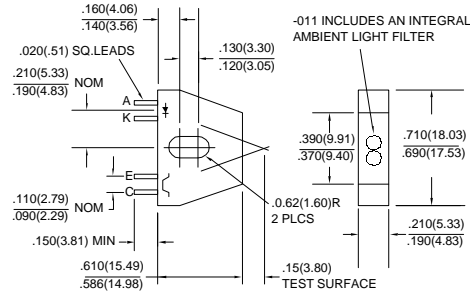
### DESCRIPTION

The HOA0708/0709 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA0708- 001, - 011) or photodarlington (HOA0709- 001, - 011) encased side- by- side on converging optical axes in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA0708- 011 and HOA0709- 011 employ an IR transmissive filter to minimize the effects of visible ambient light and provide a smooth optical face which prevents the accumulation of airborne contaminants in the optical path. The HOA0708/0709 series employs plastic molded components. For additional component information see SEP8505, SDP8405, and SDP8105.

Housing material is polycarbonate. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

### OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals  $\pm 0.010(0.25)$   
2 plc decimals  $\pm 0.020(0.51)$



DIM\_033.dwg

# HOA0708/0709

## Reflective Sensor

### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
<b>IR EMITTER</b>						
Forward Voltage	$V_F$			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	$I_R$			10	$\mu\text{A}$	$V_R=3\text{ V}$
<b>DETECTOR</b>						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$				V	$I_C=100\ \mu\text{A}$
HOA0708-001, -011		30				
HOA0709-001, -011		15				
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\ \mu\text{A}$
Collector Dark Current	$I_{CEO}$				nA	$V_{CE}=10\text{ V}$ $I_F=0$
HOA0708-001, -011				100		
HOA0709-001, -011				250		
<b>COUPLED CHARACTERISTICS</b>						
On-State Collector Current	$I_{C(ON)}$					$V_{CE}=5\text{ V}$ $I_F=40\text{ mA}$ (1)
HOA0708-001, -011		0.2				
HOA0709-001, -011		1.0				
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$				V	$I_F=40\text{ mA}$ (1) $I_C=30\ \mu\text{A}$ $I_C=125\ \mu\text{A}$
HOA0708-001, -011				0.4		
HOA0709-001, -011				1.1		
Rise And Fall Time	$t_r, t_f$				$\mu\text{s}$	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\ \Omega$ $R_L=100\ \Omega$
HOA0708-001, -011				15		
HOA0709-001, -011				75		

#### Notes

1. Test surface is Eastman Kodak neutral white test card with 90% diffuse reflectance located 0.15 in. (3.80 mm) from the front surface of the device.

### ABSOLUTE MAXIMUM RATINGS

Operating Temperature Range -40°C to 85°C  
 Storage Temperature Range -40°C to 85°C  
 Soldering Temperature (5 sec) 240°C

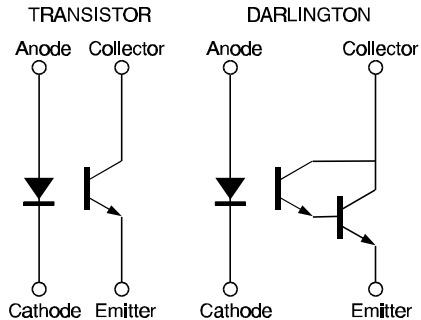
#### IR EMITTER

Power Dissipation 70 mW (1)  
 Reverse Voltage 3 V  
 Continuous Forward Current 50 mA

#### DETECTOR

	TRANS.	DARLINGTON
Collector-Emitter Voltage	30 V	15 V
Emitter-Collector Voltage	5 V	5 V
Power Dissipation	70 mW (1)	70 mW (1)
Collector DC Current	30 mA	30 mA

### SCHEMATIC



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

# Honeywell

# HOA0708/0709

## Reflective Sensor

Fig. 1 IRED Forward Bias Characteristics

gra\_073.ds4

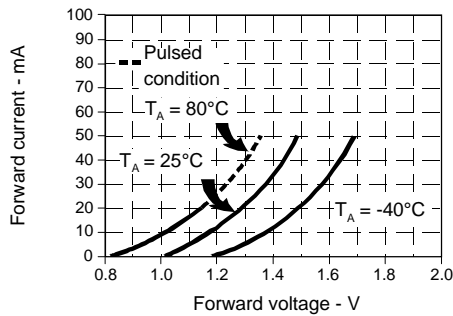


Fig. 2 Non-Saturated Switching Time vs Load Resistance

gra\_079.ds4

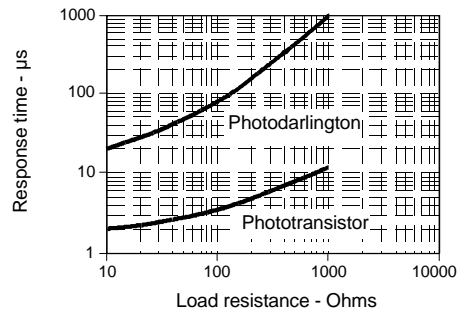


Fig. 3 Dark Current vs Temperature

gra\_301.cdr

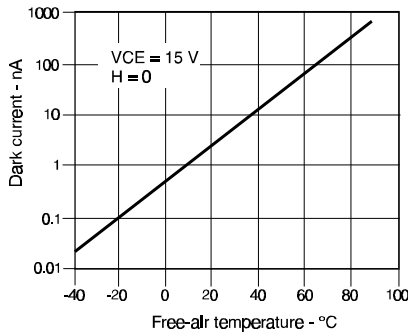


Fig. 4 Collector Current vs Ambient Temperature

gra\_076.ds4

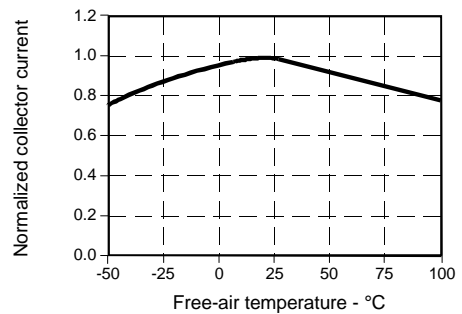


Fig. 5 Collector Current vs Distance to Reflective Surface

gra\_080.ds4

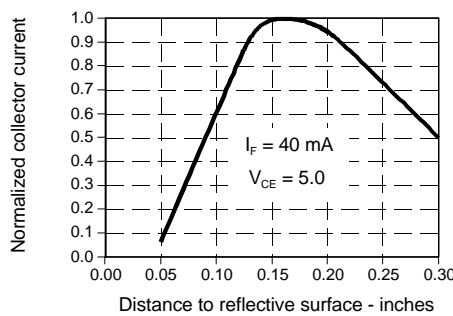
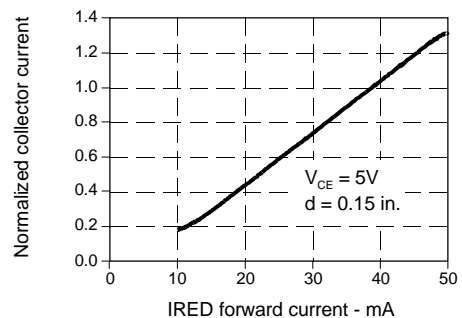


Fig. 6 Collector Current vs IRED Forward Current

gra\_081.ds4



All Performance Curves Show Typical Values

**HOA0708/0709**  
Reflective Sensor

---



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

**Honeywell**